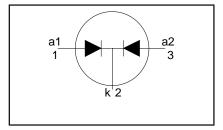
# **Rectifier diodes** ultrafast, rugged

# **BYQ30EX** series

## **FEATURES**

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
   Reverse surge capability
- High thermal cycling performance
  Isolated mounting tab

### **SYMBOL**



## **QUICK REFERENCE DATA**

$V_R = 150 \text{ V}/200 \text{ V}$
$V_F \leq 0.95 \text{ V}$
$I_{O(AV)} = 16 A$
$I_{RRM} \leq 0.2 A$
t <sub>rr</sub> ≤ 25 ns

### **GENERAL DESCRIPTION**

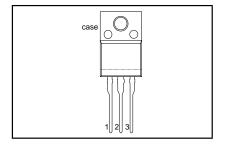
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYQ30EX series is supplied in the conventional leaded SOT186A package.

### **PINNING**

PIN	DESCRIPTION	
1	anode 1	
2	cathode	
3	anode 2	
tab	isolated	
1	l	

### **SOT186A**



# **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER CONDITIONS		MIN.	M <i>A</i>	۸X.	UNIT
V <sub>RRM</sub> V <sub>RWM</sub>	Peak repetitive reverse voltage Crest working reverse voltage	BYQ30EX	-	<b>-150</b> 150 150	<b>-200</b> 200 200	V
$V_R$	Continuous reverse voltage		-	150	200	V
I <sub>O(AV)</sub>	Average rectified output current (both diodes conducting) <sup>1</sup>	$\delta = 0.5$ ; $T_{hs} \le 59  ^{\circ}C$	-	1	6	A
I <sub>FRM</sub>	Repetitive peak forward current per diode	$t = 25 \mu s; \delta = 0.5;$ $T_{hs} \le 59 ^{\circ}C$	-	1	6	Α
I <sub>FSM</sub>	Non-repetitive peak forward	t = 10 ms	-		00	Α
	current per diode	t = 8.3 ms sinusoidal; with reapplied V <sub>RWM(max)</sub>	-	11	10	A
I <sub>RRM</sub>	Repetitive peak reverse current per diode	$t_p = 2 \mu s; \delta = 0.001$	-	0.	.2	Α
I <sub>RSM</sub>	Non-repetitive peak reverse current per diode	t <sub>p</sub> = 100 μs	-	0.	.2	Α
$egin{array}{c} T_{\mathrm{stg}} \ T_{\mathrm{j}} \end{array}$	Storage temperature Operating junction temperature		-40 -		50 50	°C

### **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>C</sub>	9	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

<sup>1</sup> Neglecting switching and reverse current losses.

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# **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs}$  = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	1		2500	V
C <sub>isol</sub>	Capacitance from T2 to external heatsink	f = 1 MHz	1	10	-	pF

## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-hs}$ $R_{th j-a}$	heatsink	with heatsink compound without heatsink compound in free air	- - -	- - 55	5.0 7.0 -	K/W K/W K/W

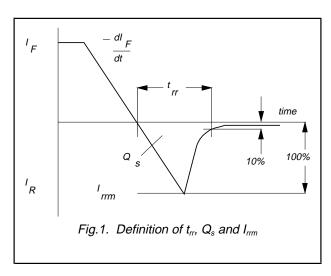
## **ELECTRICAL CHARACTERISTICS**

characteristics are per diode at T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	$I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.83	0.95	V
		$I_F = 16 \text{ A}; T_i = 150^{\circ}\text{C}$	-	1.0	1.15	V
		$ I_{\rm F}  = 16  \text{A};$	-	0.98	1.25	
I <sub>R</sub>	Reverse current	$V_R = V_{RWM}$ ; $T_i = 100 ^{\circ}C$	-	0.3	0.6	mA
		$V_R = V_{RWM}$	-	2	30	μA nC
$Q_s$	Reverse recovery charge	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A/}\mu\text{s}$	-	4	11	nC
l t <sub>rr</sub>	Reverse recovery time	$I_{\rm F} = 1 \text{ A}; V_{\rm R} \ge 30 \text{ V};$	-	20	25	ns
		$-dI_{F}/dt = 100 A/\mu s$				
I I <sub>rrm</sub>	Peak reverse recovery current	$I_{\rm F} = 1 \text{ A}; V_{\rm R} \ge 30 \text{ V};$	-	1.0	2	Α
		$-dI_{F}/dt = 50$ A/ $\mu$ s; $T_{i} = 100$ °C				
$V_{fr}$	Forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	1	-	V

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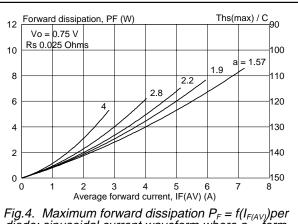
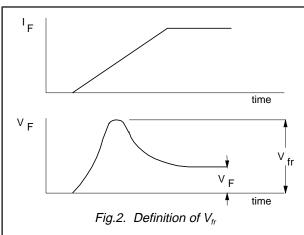
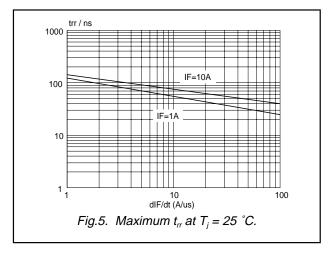
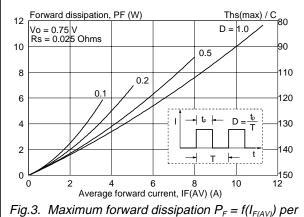


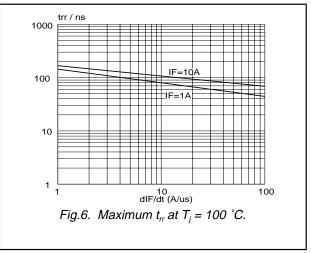
Fig.4. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; sinusoidal current waveform where a = f orm factor  $= I_{F(RMS)} / I_{F(AV)}$ .





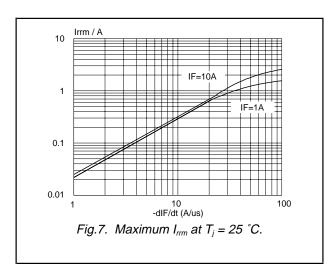


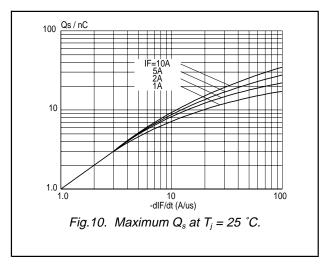
Average forward current, IF(AV) (A) Fig.3. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

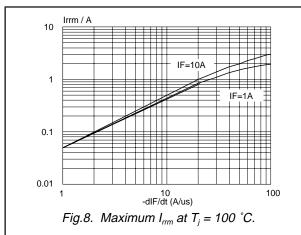


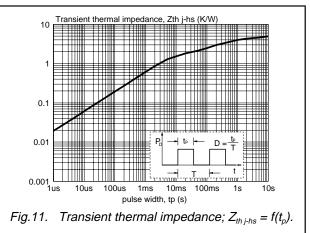
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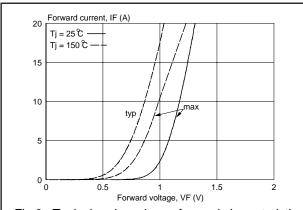
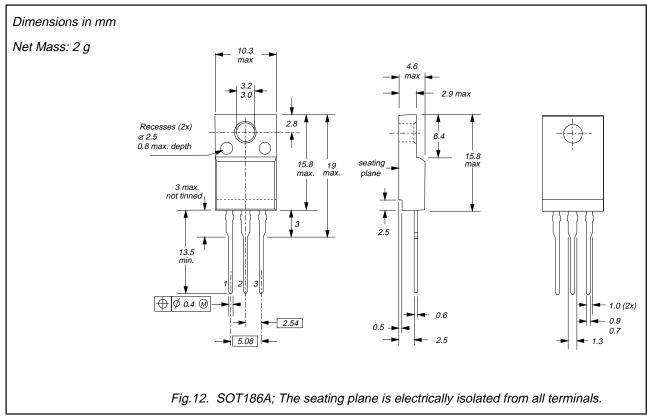


Fig.9. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

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## **MECHANICAL DATA**



# Notes

- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

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### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

### Application information

Where application information is given, it is advisory and does not form part of the specification.

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